## FOR USE BY ELECTRICIANS OVERSEAS:

**EXELOIDE STATE** (New Transistor Manual) lists all the transistors registered with the Electronic Industries Association of Japan (EIAJ), arranged in a manner easy to look up. We hope that you will make full use of the data provided in this manual by referring to the Japanese-English translation key given below.

	大定格 (T <sub>e</sub> = 25°C)	電気的特性(T <sub>a</sub> = 25°C) 外
型名社名用 途構造 VCBO (V)	VCEO IC PC Tj ICBO 数大值	直流またはバルス hFE バイアス hje hie hre hee feb Cob Tbb 備考
1 2 3 4		
TYPE NUMBER * INDICATES VALUE IN GROUNDED-		
2 ORIGINAL M	IANUFACTURER	BASE OPERATION, OTHERWISE
3 USES		VALUE IN EMITTER-GROUNDED
4 MATERIAL	AND STRUCTURE	OPERATION.
5 MAXIMUM	RATINGS	9 $fab$ OF RF CHARACTERISTIC, EXCEPT
6 I CBO MAXIN	IUM VALUE AND V CB	IN CASE OF <b>*</b> WHICH INDICATES
VALUE (CRI	TERIA FOR MEASURING	VALUE OF $f_r$ .
I сво )		$\mathbf{IO}$ Cob and $\tau_{bb}$ of RF characteris
7 STANDARD	VALUE OF DC/PULSE	TICS EXCEPT IN CASE OF $*$ IN $\tau_{bb'}$
$h_{FE}$ AND $V_{C}$	$\varepsilon$ , $I_c$ (CRITERIA FOR	COLUMN WHICH INDICATES VALUE
MEASURING	$FDC/PULSE h_{FE}$ )	OF hie (real)
8 STANDARD	VALUE OF h PARAME-	II OUTLINE
TERS AND BIAS $V_{CB}$ , $I_{\varepsilon}$ (CRITERIA		12 REMARKS
FOR MEASU	URING h PARAMETERS)	:とコンプリ: COMPLEMENTARY TO